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SUPPLEMENTAL **INFORMATION** DISCLOSURE STATEMENT BY APPLICANT

Sheet I of I

	COMPLETE IF KNOWN
Application Number	10/650,282
Filing Date	August 28, 2003
First Named Inventor	Tianniu CHEN
Art Unit	1621
Examiner Name	Samuel A. Barts
Attorney Docket Number	2771-515-CIP

	U.S. PATENT DOCUMENTS										
Examiner Initials*	Cite No.	Document Number	Publication Date MM-DD-YYYY	Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document						
5/12		US-6,858,697		02-22-2005	Mayorga et al.						
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Examiner signature	Date Considered	11/1	105
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^{*}Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

All the foreign patents and publications that are not written in English language are accompanied by their respective English abstracts, which constitute concise explanation of relevance of the non-English patents and publications that satisfy the requirements of 37 C.F.R. §1.98(a)(3)(i), according to MPEP 609 III A(3).

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INFORMATION DISCLOSURE STATEMENT			Tianniu Chen, et al.							
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				U.S. 1	PATENT DOCUMENTS					
EXAMI INITI			PATENT NUMBER	ISSUE DATE	NAME	CL	ASS	SUBCLASS	FILING IF APPRO	
7	14	AA	5,204,134	4/20/1993	Kirlin, et al.	J	_	7		
.7/	/	AB	5,536,323	7/16/1996	Kirlin, et al.	\prod				
		AC	5,711,816	1/27/1998	Kirlin, et al.	1				
		AD	6,171,945	1/9/2002	Mandal, et al.			1		
		AE	4,745,169	5/17/1988	Sugiyama, et al.	\top		/		
		AF	4,755,370	7/5/1988	Kray, et al.	\top				
		AG	6,114,500	9/5/2000	Mori, et al.	1	7			
		AH	5,043,789	8/27/1991	Linde, et al.		$\forall I$		**********	
		AI	4,871,616	10/3/1989	Kimura, et al.		\forall			
		AJ	5,484,867	1/16/1996	Lichtenhan, et al.		Λ			
		AK	4,670,299	6/2/1987	Fukuyama, et al.		71	<u> </u>		
		AL	5,047,492	9/10/1991	Weidner, et al.		1 1			
		AM	5,210,250	5/11/1993	Watanuki, et al.		1	<u> </u>		
		AN	4,374,110	2/15/1983	Darnell, et al.					
		AO	4,156,689	5/29/1979	Ashby, et al.					
GA	1	AP	5,804,040	9/8/1998	Asai, et al.	1	\dashv	7		
11				FOREIG	N PATENT DOCUMENTS					
			DOCUMENT	PUBLICATION					TRANSL	ATION
			NUMBER	DATE	COUNTRY	CI	LASS	SUBCLAS S	YES	NO
									X	
									(abstract only)	
61	K	AQ	JP 50-111198	1/28/1974	Japan				X	-
	_		OTHER DOCUM	AENTS (Includi	ing Author, Title, Journal-Da	ate, P	age N	(umber, Etc.)		
5/	1	AR	Mantz, et al., "T	hermolysis of Po	lyhedral Oligomeric Silsesquic					
Siloxane Copolymers", Chem. Ma AS Ravi K. Laxman, Neil Hendrix Ba			аггу Arkles, Теггу А. Tabler "S	Synth	esizin	g Low-K CVI) Materials	for Fab		
77			Use" Semicondu	ctor Internationa	1, 11/1/2000			· .		
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			August 28, 2003	TBA		
	07	THER DOCUMENTS (Including				
11	AT .					
31		Vol. 612, 2000 Materials Research				
511	ΑÜ	Albert Wang, et al. "TMCTS for	r Gate Dielectric in Thin Film Transistors", Mat. Res. Soc. Meeting 1996			
11	ΑV			nced Chemical Vapor Deposition", Applied		
9/	ļ	Physics Letters, Vol. 79, No. 6, A				
		, ·	Continue on Page			
EXAMINE	X //	7		DATE CONSIDERED		
51	12	2 4 9		11/7/03		
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4	XAMINA		PATENT NUMBER	ISSUE DATE	NAME	CLASS	SUBCLASS	FILING IF APPRO	PRIATE	
	1/3	BA	10/015,326		Chongying Xu, et al.	F-	7	12/31/200	1	
	3/3	BB	10/301,109		Alexander S. Borovik			11/21/200	2	
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		,			N PATENT DOCUMENT	rs .				
			DOCUMENT NUMBER	PUBLICATION DATE	COUNTRY	CLASS	SUBCLAS	TRANSL YES	ATION NO	
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1	MATAL	L	NUMBER	ISSUE DATE	NAME	CLASS	SUBCLASS	IF APPRO	PRIATE		
3	15	AA	2004/054114A	3/18/2004	Mayorga, et al.	1+-					
	/	AB	4,087,448	05/1978	Rossmy, et al.		/				
		AC	4,127,598	11/1978	McEntee						
		AD	4,764,631	8/1988	Halm, et al.						
		AE	5,312,947	5/1994	Tsukuno, et al.	1	1				
		AF	6,368,359	4/2002	Perry, et al.		X				
-		AG	5,276,173	1/1994	Marko, et al.	1 /					
-		AH	5,098,865	3/1992	Machado, et al.	1-/	_				
-		AI	6,331,494	12/18/2001	Olson, et al.	1 /					
-		AJ	6,147,009	11/14/2000	Grill, et al.	1-/-					
	3/2	AK	6,484,082	11/26/2002	Cho, et al.			·			
			1	FOREIC	ON PATENT DOCUMENTS			1			
			DOCUMENT NUMBER	PUBLICATION DATE	COUNTRY	CLASS	SUBCLAS	TRANSL YES	ATION NO		
	7	-						X (abstract only)	Ē		
	5/6	AL	1321469A	6/25/2003	E.P.	1					
1	//- //-	AM	2004/027110A	4/1/2004	wo						
	/	AN	98/15499A	4/16/1998	wo						
	11	AO	0543665	5/1993	E.P.	1/	1)	* -			
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